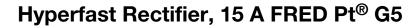
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LINKS TO ADDITIONAL RESOURCES



PRIMARY CHARACTERISTICS								
I _{F(AV)}	15 A							
V _R	1200 V							
V _F at I _F at 125 °C	2.1 V							
t _{rr}	29 ns							
T _J max.	175 °C							
Package	D ² PAK 2L (TO-263AB 2L)							
Circuit configuration	Single							

FEATURES

- Hyperfast and optimized Q_{rr}
- Best in class forward voltage drop and switching RoHS
 losses trade off
 HALOGEN
- Optimized for high speed operation
- 175 °C maximum operating junction temperature
- · Polyimide passivation
- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 $^{\circ}\mathrm{C}$
- Designed and qualified according to JEDEC®-JESD 47
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

DESCRIPTION / APPLICATIONS

Featuring a unique combination of low conduction and switching losses, this rectifier is the right choice for high frequency converters, both soft switched / resonant. Specifically designed to improve efficiency of PFC and output rectification stages of EV / HEV battery charging stations, booster stage of solar inverters and UPS applications, these devices are perfectly matched to operate with MOSFETs or high speed IGBTs.

MECHANICAL DATA

Case: D²PAK 2L (TO-263AB 2L)

Molding compound meets UL 94 V-0 flammability rating

Terminals: matte tin plated leads, solderable per J-STD-002

ABSOLUTE MAXIMUM RATINGS										
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS						
Repetitive peak reverse voltage	V _{RRM}		1200	V						
Average rectified forward current	I _{F(AV)}	T _C = 98 °C, D = 0.50	15							
Repetitive peak forward current	I _{FRM}	T _C = 98 °C, D = 0.50, f = 20 kHz	30	А						
Non-repetitive peak surge current	I _{FSM}	$T_C = 45 \text{ °C}, t_p = 10 \text{ ms}$, sine wave	110							
Operating junction and storage temperature	T _J , T _{Stg}		-55 to +175	°C						

ELECTRICAL SPECIFICATIONS ($T_J = 25$ °C unless otherwise specified)										
PARAMETER	MIN.	TYP.	MAX.	UNITS						
Breakdown voltage, blocking voltage	V _{BR} , V _R	I _R = 100 μA	1200	-	-					
	V _F	I _F = 15 A	-	2.5	3.3	V				
Forward voltage		I _F = 15 A, T _J = 125 °C	-	2.1	-					
Reverse leakage current	I _R	$V_{R} = V_{R}$ rated	-	-	50					
neverse leakage current		$T_J = 125 \text{ °C}, V_R = V_R \text{ rated}$	-	-	500	μA				
Junction capacitance	CT	V _R = 200 V	-	10	-	pF				
Series inductance	L _S	Measured to lead 5 mm from package body	-	8	-	nH				

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 1
 Document Number: 97026

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DYNAMIC RECOVERY CHARACTERISTICS ($T_J = 25$ °C unless otherwise specified)										
PARAMETER	SYMBOL	TEST	CONDITIONS	MIN.	TYP.	MAX.	UNITS			
		$I_F = 1.0 \text{ A}, dI_F/c$	$dt = 100 \text{ A/}\mu\text{s}, \text{V}_{\text{R}} = 30 \text{ V}$	-	29	-				
Reverse recovery time	t _{rr}	T _J = 25 °C		-	96	-	ns			
		T _J = 125 °C		-	137	-				
Peak recovery current	1	T _J = 25 °C	I _F = 10 A dI _F /dt = 600 A/μs	-	11.5	-	А			
	I _{RRM}	T _J = 125 °C	$A_{\rm IF}/at = 600 {\rm A}/{\rm \mu s}$ V _R = 400 V	-	16	-				
Reverse recovery charge	Q _{rr}	T _J = 25 °C		-	375	-	nC			
Reverse recovery charge		T _J = 125 °C		-	900	-				
Reverse recovery time	t _{rr}	T _J = 25 °C		-	77.5	-	ns			
neverse recovery time		T _J = 125 °C		-	106	-				
Book recovery ourrent	I _{RRM}	T _J = 25 °C	$I_{\rm F} = 15 {\rm A}$	-	21	-	A			
Peak recovery current		T _J = 125 °C	dI _F /dt = 1000 A/µs V _B = 800 V	-	29	-				
	0	T _J = 25 °C		-	680	-	nC			
Reverse recovery charge	Q _{rr}	T _J = 125 °C		-	1600	-				

THERMAL - MECHANICAL SPECIFICATIONS										
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS				
Thermal resistance, junction-to-case	R _{thJC}		-	-	1.7	°C/W				
Weight			-	2.0	-	g				
Mounting torque			6.0 (5.0)	-	12 (10)	kgf · cm (lbf · in)				
Maximum junction and storage temperature range	T _J , T _{Stg}		-55	-	175	°C				
Marking device		Case style D ² PAK 2L (TO-263AB 2L)	E5TX1512S							



VS-E5TX1512S2L-M3

Vishay Semiconductors

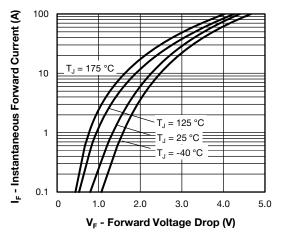


Fig. 1 - Forward Voltage Drop Characteristics

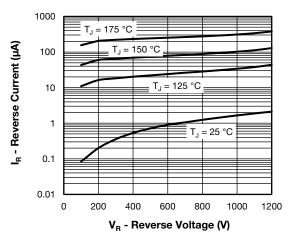


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

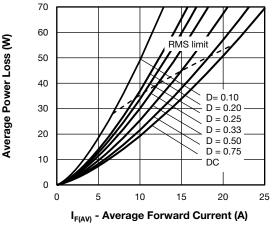


Fig. 5 - Forward Power Loss Characteristics

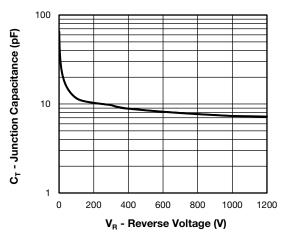


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

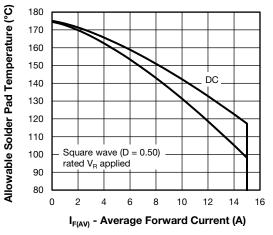


Fig. 4 - Maximum Allowable Case Temperature vs. Average Forward Current

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 3
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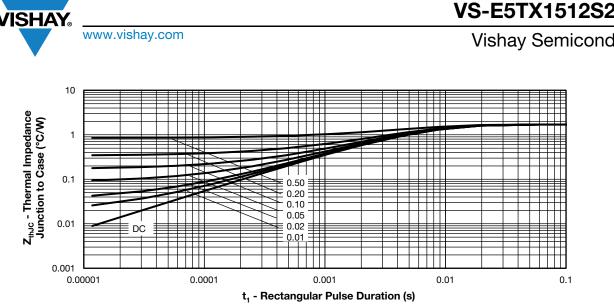


Fig. 6 - Transient Thermal Impedance, Junction to Case

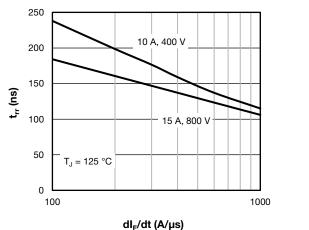
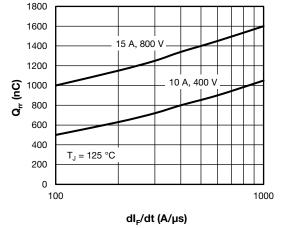
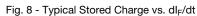


Fig. 7 - Typical Reverse Recovery Time vs. dl_F/dt





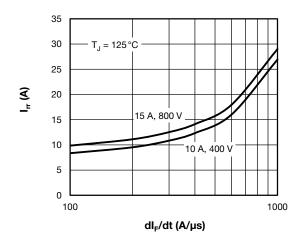


Fig. 9 - Typical Recovery Current vs. dI_F/dt





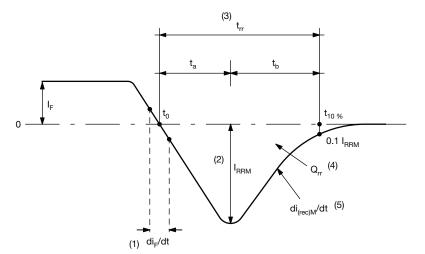


Fig. 10 - Reverse Recovery Waveform and Definitions

Notes

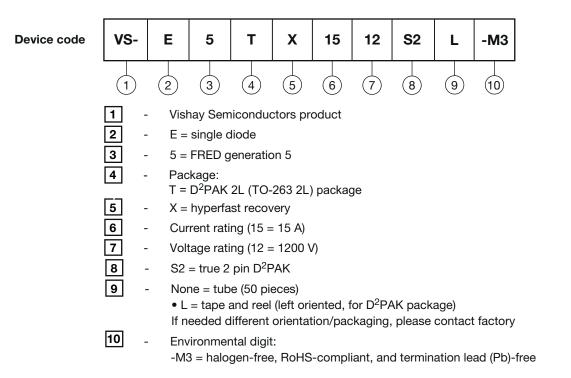
- $^{(1)}$ di_F/dt rate of change of current through zero crossing
- ⁽²⁾ I_{RRM} peak reverse recovery current
- $^{(3)}$ t_{rr} reverse recovery time measured from t₀, crossing point of negative going I_F, to point t_{10%}, 0.1 I_{RRM}
- $^{(4)}~~Q_{rr}$ area under curve defined by t_0 and $t_{10~\%}$

$$Q_{rr} = \int_{t_0}^{t_{10\%}} I(t)dt$$

⁽⁵⁾ di_(rec)M/dt - peak rate of change of current during t_b portion of t_{rr}



ORDERING INFORMATION TABLE



ORDERING INFORMATION (Example)								
PREFERRED P/N	BASE QUANTITY PACKAGING DESCRIPTION							
VS-E5TX1512S2L-M3	800	13" diameter reel						

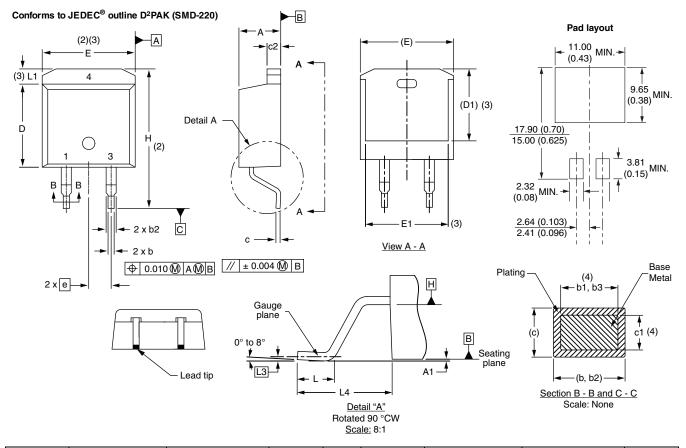
LINKS TO RELATED DOCUMENTS							
Dimensions www.vishay.com/doc?96683							
Part marking information	www.vishay.com/doc?96693						
Packaging information	www.vishay.com/doc?95032						





D²PAK 2L (TO-263AB 2L)

DIMENSIONS in millimeters and inches



SYMBOL	MILLIMETERS		INC	INCHES			NOTES	SYMBOL	MILLIM	IETERS	INC	HES	NOTES
STMBOL	MIN.	MAX.	MIN.	MAX.	NOTES	NOTES	STWDUL	MIN.	MAX.	MIN.	MAX.	NOTES	
А	4.06	4.83	0.160	0.190			D1	6.86	8.00	0.270	0.315	3	
A1	0.00	0.254	0.000	0.010			Е	9.65	10.67	0.380	0.420	2, 3	
b	0.51	0.99	0.020	0.039			E1	7.90	8.80	0.311	0.346	3	
b1	0.51	0.89	0.020	0.035	4		е	2.54	BSC	0.100	BSC		
b2	1.14	1.78	0.045	0.070			Н	14.61	15.88	0.575	0.625		
b3	1.14	1.73	0.045	0.068	4		L	1.78	2.79	0.070	0.110		
с	0.38	0.74	0.015	0.029			L1	-	1.65	-	0.066	3	
c1	0.38	0.58	0.015	0.023	4		L3	0.25 BSC		0.010	BSC		
c2	1.14	1.65	0.045	0.065			L4	4.78	5.28	0.188	0.208		
D	8.51	9.65	0.335	0.380	2								

Notes

⁽¹⁾ Dimensioning and tolerancing per ASME Y14.5 M-1994

(2) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body
 (3) Thermal and contain antional within dimension E 1.1, D1 and E1.

⁽³⁾ Thermal pad contour optional within dimension E, L1, D1 and E1

⁽⁴⁾ Dimension b1 and c1 apply to base metal only

⁽⁵⁾ Datum A and B to be determined at datum plane H

⁽⁶⁾ Controlling dimension: inch

(7) Outline conforms to JEDEC® outline TO-263AB

Revision: 14-Mar-2022

1

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